500-4000 MHz High Power Amplifier



Device Features

- OIP3 = 49.0 dBm @ 1900 MHz
- Gain = 12.5 dB @ 1900 MHz
- Output P1 dB = 30.3 dBm @ 1900 MHz
- 50 Ω Cascadable
- Patented Over Voltage Protection Circuit
- Lead-free/RoHS-compliant SOIC-8 package

NC Output Input GND GND GND

YY = Year, WW = Work week,

XX = Wafer Number

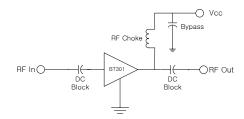
Product Description

BeRex's BT301 is a high power and a high dynamic range amplifier in a low cost surface mount package(SOIC-8) with a RoHS-compliant, that incorporates reliable heterojunction-bipolar-transistor (HBT) devices fabricated with InGaP GaAs technology. This device is designed for use where high linearity is required and features high OIP3 and Power with low consumption current (350mA) and requires a few external matching components such as a DC blocking capacitors on the In/Output pin, a bypass capacitor and a RF choke for the out port. All devices are 100% RF/DC tested.

Applications

- Base station Infrastructure/RFID
- Commercial/Industrial/Military wireless system

Application Circuits



^{*}external matching circuit: refer to the page 4 to 11.

Typical Performance¹

Parameter		Unit				
	900	1900	2140	2450	3500	MHz
Gain	18.5	12.5	11.5	10.5	7.6	dB
S11	-15	-18	-18	-12	-23.2	dB
S22	-7	-12	-12	-11	-17.4	dB
OIP3 ²	49	49	47	49	42.5	dBm
P1dB	29.5	30.3	30.3	30.3	27.9	dBm
IS-95C ACPR	22.5	22.5	-	-	-	dBm
WCDMA ACLR	-	-	21	21	18.4	dBm
Noise Figure	8.5	8.6	7.5	7.5	7.3	dB

¹ Device performance _ measured on a BeRex evaluation board at 25°C, 50 Ω system.

^{*}ACLR Test set-up: 3GPP WCDMA, TM1+64DPCH, +5MHz offset.

	Min.	Typical	Max.	Unit
Bandwidth	500		4000	MHz
I _c @ (Vc = 5V)	310	350	390	mA
V _C		5.0		V
R _{TH}		19.6		°C/W

Absolute Maximum Ratings

Parameter	Rating	Unit
Operating Case Temperature	-40 to +85	°C
Storage Temperature	-55 to +155	°C
Junction Temperature	+220	°C
Operating Voltage	+6.0	V
Supply Current	600	mA
Input RF Power	28	dBm

^{*}Operation of this device above any of these parameters may result in permanent damage.

BeRex

•website: www.berex.com

email: <u>sales@berex.com</u>

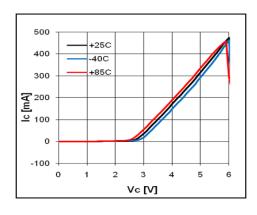
 $^{^{2}\,}$ OIP3 $_$ measured with two tones at an output of 16 dBm per tone separated by 1 MHz.

^{*}ACPR&ACLR CH Power _ measured at 50dBc.

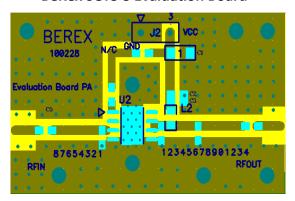
^{*}ACPR Test set-up: IS-95 CDMA, 9Ch. FWD, +885KHz offset.



V-I Characteristics



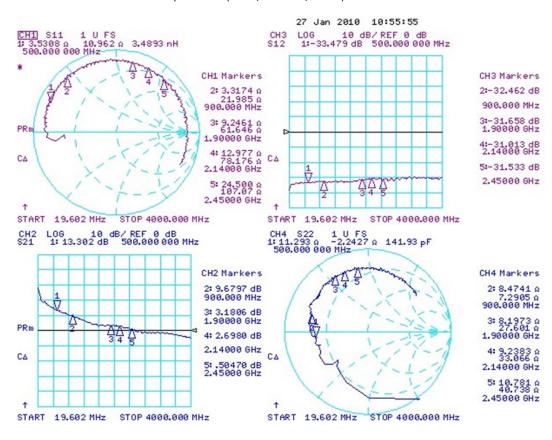
BeRex SOIC-8 Evaluation Board



*Dielectric constant 4.2 *RF pattern width 52mil *31mil thick FR4 PCB

Typical Device Data

S-parameters (Vc=5V, Ic=340mA, T=25°C)



500-4000 MHz High Power Amplifier



S-Parameter

(Vdevice = 5.0V, Icc = 340mA, T = 25 °C, calibrated to device leads)

Freq [MHz]	S11 [Mag]	\$11 [Ang]	S21 [Mag]	S21 [Ang]	\$12 [Mag]	\$12 [Ang]	S22 [Mag]	S22 [Ang]
[141112]	[IAIMP]	נאייא	[IAIGP]	נאייאן	[IAIGP]	נאייאן	[IAIMP]	נאייא
100	0.842	-178.0	11.489	131.4	0.019	18.2	0.534	-134.7
500	0.895	157.3	4.894	104.8	0.023	10.6	0.659	-176.7
1000	0.893	130.8	2.766	83.9	0.022	9.8	0.754	160.4
1500	0.870	106.2	1.658	75.1	0.025	21.7	0.773	139.8
2000	0.852	82.2	1.512	64.0	0.027	21.5	0.761	120.1
2500	0.840	58.8	1.047	47.2	0.026	21.6	0.773	101.7
3000	0.841	35.6	0.888	50.8	0.029	16.4	0.792	83.2
3500	0.850	12.5	0.840	36.8	0.031	23.4	0.659	62.6
4000	0.879	-6.4	0.542	24.0	0.031	16.3	0.634	41.3

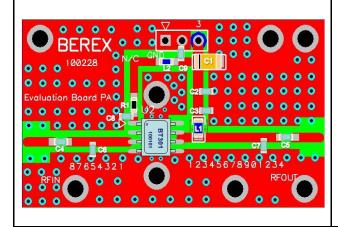


Application Circuit: 900 MHz

Schematic Diagram		вом		Toler- ance
	C1	1206	10uF	±20%
Vcc	C2	0603	1.0nF	±5%
C3 — C2 — C1 E2	C3	0603	100pF	±5%
	C4	0603	3pF	±5%
	C5	0603	100pF	±5%
C8 > }	C6	0603	4.7pF	±5%
ı ı ı ı ı ı ı ı ı ı ı ı ı ı ı ı ı ı ı	C7	0603	5.0pF	±5%
RF_IN RF_OUT	C8	0603	2.7pF	±5%
C5 C4 C6 = 5.6mm - C4 C5	R1	0603	12ohm	±5%
7 3.011111	L1	1008	56nH	±5%
_ _ _ _ _	L2	0603	4.7nH	±5%
	·			

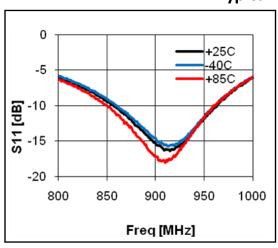
PCB Diagram

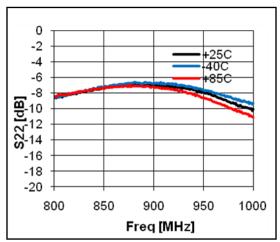
Notice

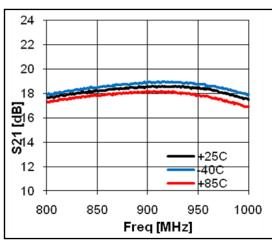


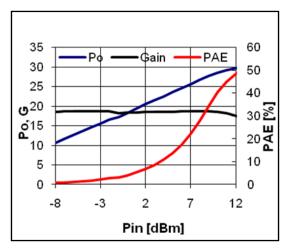
- 1. PCB: 31mil thick FR4
- Distance between the center of the shunt Inductor(C6) and the input pin of BT301 <u>5.6 mm</u>.
- Distance between the center of the shunt cap.
 (C7) and the output pin of BT301 <u>12 mm</u>.
- ****** BT301 with both input and output ports opened simultaneously may cause instability. Please See an application note or contact company for application support.

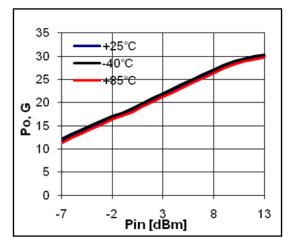


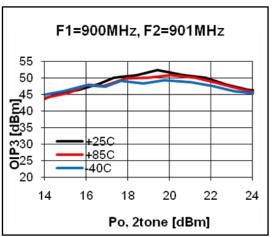












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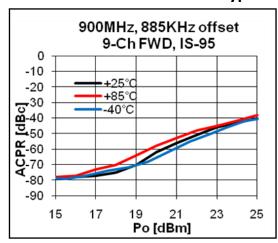
•website: www.berex.com

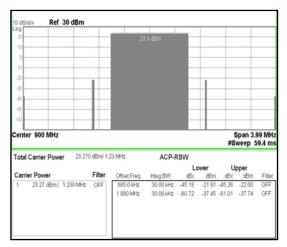
• email: sales@berex.com

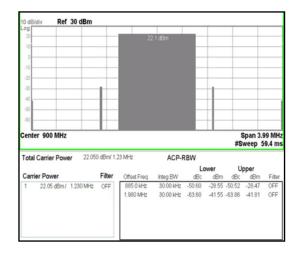
500-4000 MHz High Power Amplifier

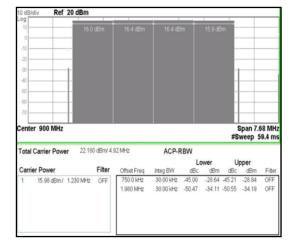


Typical Performance









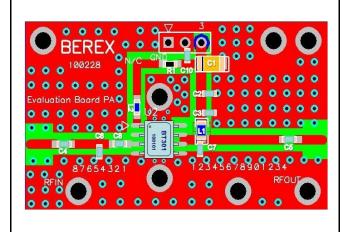


Application Circuit: 1900 MHz

Schematic Diagram		вом		Toler- ance
	C1	1206	10uF	±20%
Vcc	C2	0603	1nF	±5%
		0603	100pF	±5%
$\begin{cases} -1 & \text{if } 1 \\ \text{if } 1 \\ \text{if } 1 \end{cases}$	C4	0603	100pF	±5%
	C5	0603	100pF	±5%
	C6	0603	3pF	±5%
1.6mm \(\)	C7	0603	2.5pF	±5%
RF_OUT	C8	0603	2.5pF	±5%
C5	R1	0603	12 ohm	±5%
C6 + 4.0mm + C7 + 2.511111 C7 +	L1	1008	56nH	±5%
_	L2	0603	6.8nH	±5%
	•	•		

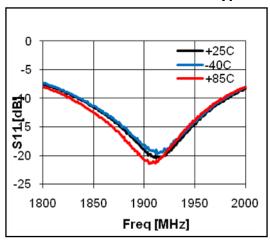
PCB Diagram

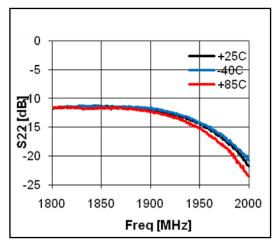
Notice

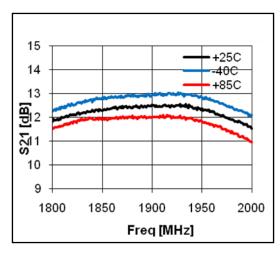


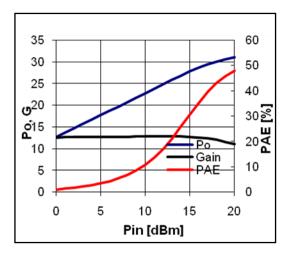
- 1. PCB: 31mil thick FR4
- Distance between the center of the series cap.
 (C8) and the input pin of BT301 _ <u>1.6 mm</u>.
- Distance between the center of the shunt cap.
 (C6) and the input pin of BT301 _ 4.0 mm.
- Distance between the center of the shunt cap.
 (C7) and the output pin of BT301 _ <u>2.5 mm</u>.

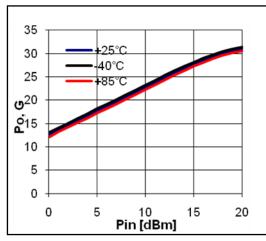


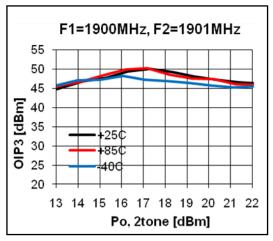






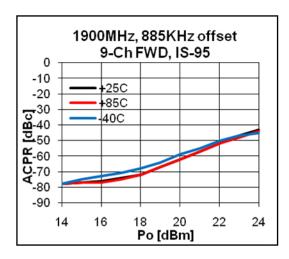


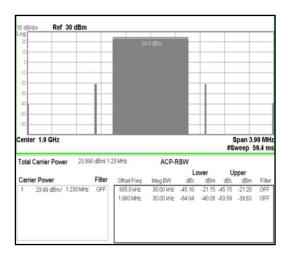


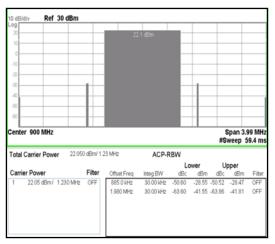


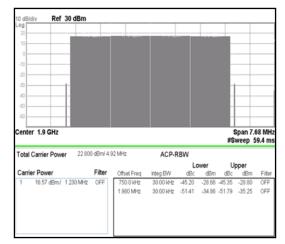
500-4000 MHz High Power Amplifier











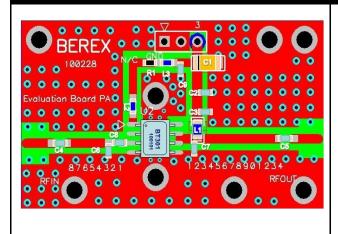


Application Circuit: 2140MHz

Schematic Diagram		вом		Toler- ance
	C1	1206	10uF	±20%
Vcc	C2	0603	1nF	±5%
+ C3 + C2 → C1		0603	100pF	±5%
$\begin{cases} 1 & \text{All } \\ 1 & \text{All } \end{cases} = \begin{bmatrix} 1 & \text{All } \\ 1 & \text{All } \end{bmatrix}$	C4	0603	100pF	±5%
	C5	0603	100pF	±5%
}	C6	0603	2.5pF	±5%
1.6mm NC	C 7	0603	1.8pF	±5%
C8 P RF_OUT	C8	0603	1.8pF	±5%
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	C9	0603	5.0pF	±5%
C6 = 3.0mm	R1	0603	12 ohm	±5%
<u> </u>	L1	1008	56nH	±5%
	L2	0603	4.7nH	±5%

PCB Diagram

Notice



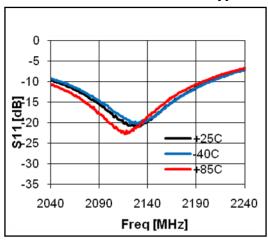
- 1. PCB: 31mil thick FR4
- Distance between the center of the shunt cap.
 (C8) and the input pin of BT301 _ <u>1.6 mm</u>.
- Distance between the center of the shunt cap.
 (C6) and the input pin of BT301 _ <u>3.0 mm</u>.
- Distance between the center of the shunt cap.
 (C7) and the output pin of BT301 _ <u>2.5 mm</u>.

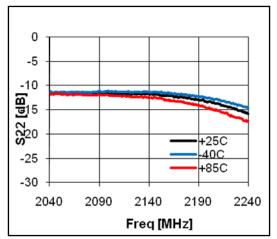
BeRex

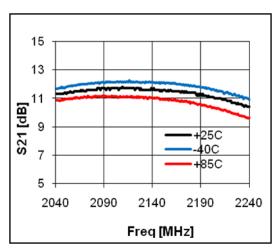
•website: www.berex.com

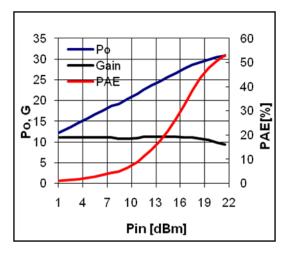
• email: sales@berex.com

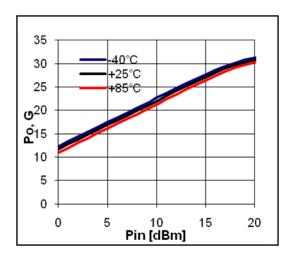


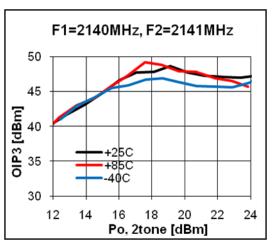












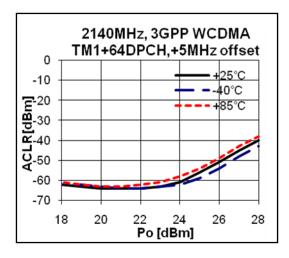
BeRex

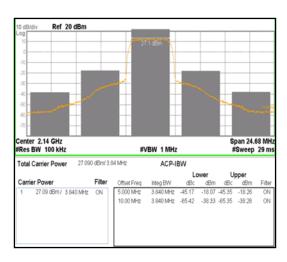
•website: www.berex.com

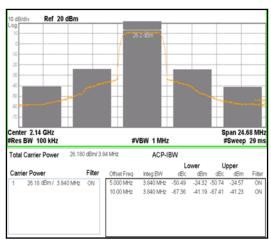
• email: sales@berex.com

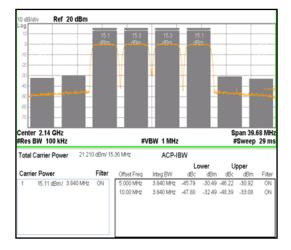
500-4000 MHz High Power Amplifier





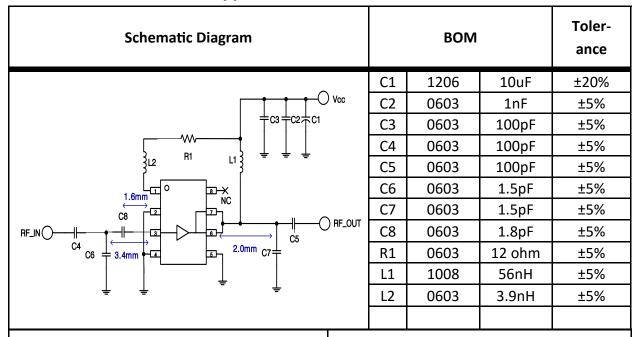






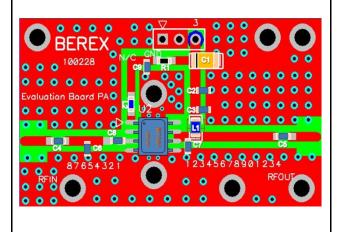


Application Circuit: 2450MHz



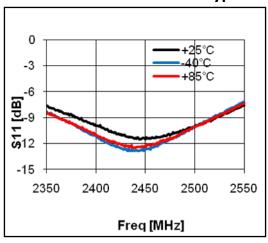
PCB Diagram

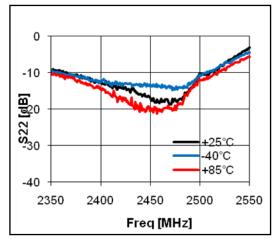
Notice

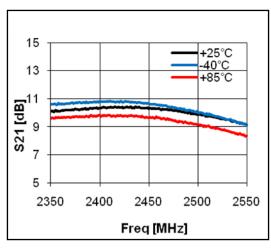


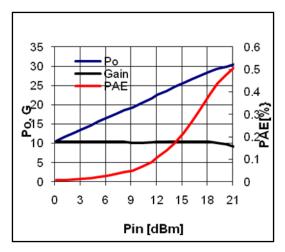
- 1. PCB: 31mil thick FR4
- Distance between the center of the series cap.
 (C8) and the input pin of BT301 _ <u>1.6 mm</u>.
- Distance between the center of the shunt cap.
 (C6) and the input pin of BT301 _ <u>3.4 mm</u>.
- Distance between the center of the shunt cap.
 (C7) and the output pin of BT301 _ 2.0 mm.

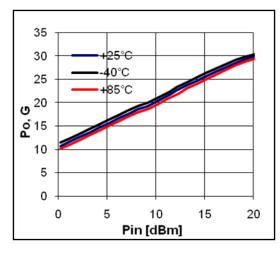


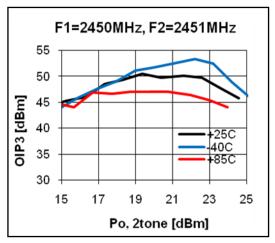






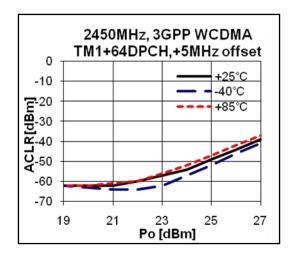


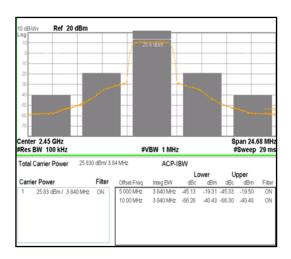


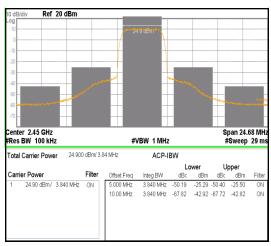


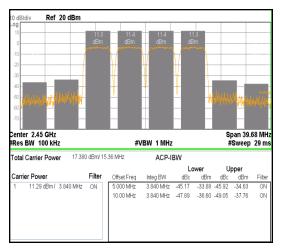
500-4000 MHz High Power Amplifier





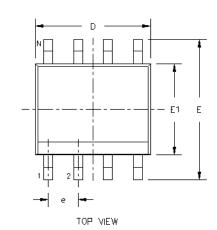


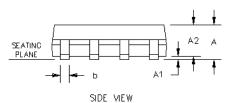


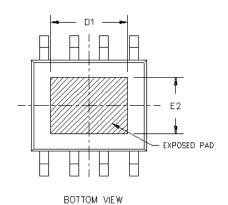


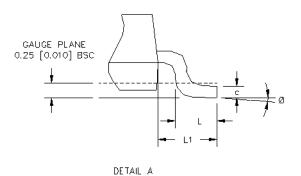


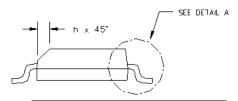
Package Outline Dimension











	DIMENSION IN INCHES			DIME	nsion in	I MM
SYM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.056	0.058	0.061	1,42	1,47	1,55
A1	0.001	0.004	0.005	0.025	0.102	0.127
A2	0.051	0.054	0.057	1,30	1,37	1,45
Ь	0.014	0.016	0.020	0.36	0,41	0.51
c	0.007	0.008	0.010	0.18	0.20	0.25
D	0,191	0.193	0.195	4.85	4.90	4,95
E1	0.151	0.153	0.155	3 84	3.89	3.94
Е	0.234	0.240	0,244	5.94	6,10	6,20
e		0.050		1.27		
L	0.020	0.027	0.032	0.51	0.69	0.81
L1	0.042	0.044	0.046	1,07	1,12	1,17
Ø	0.	-	8.	0"	-	8.
h	0.011	0.015	0.019	0.28	0.38	0.48
D1	0.120	_	0.130	3.05	-	3,30
E2	0.085	_	0 095	2.16	_	2.41

- NOTES:

 1. DIMENSION D DOES NOT INCLUDE MOLD FLASH.
 PROTRUSIONS OR GATE BURRS. DIMENSION ET DOES
 NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.

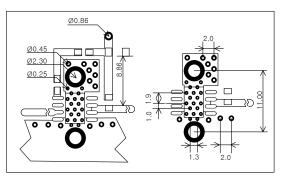
 2. COPLANARITY APPLIES TO THE TERMINALS.
 COPLANARITY SHALL NOT EXCEED 0.003" [0.08 mm]
- 3. BASED FROM JEDEC MS-012 VARIATION AA.

500-4000 MHz High Power Amplifier

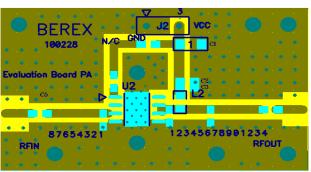


Suggested PCB Land Pattern and PAD Layout

PCB Land Pattern



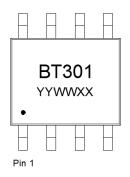
PCB Mounting



Note: All dimension are in millimeters

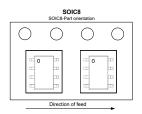
PCB lay out _ on BeRex website

Package Marking



YY = Year, WW = Working Week, XX = Wafer No.

Tape & Reel



Packaging information:

Tape Width (mm): 12

Reel Size (inches): 7

Device Cavity Pitch (mm): 8

Devices Per Reel: 1000

BeRex

•website: www.berex.com

• email: sales@berex.com

500-4000 MHz High Power Amplifier



Lead plating finish

100% Tin Matte finish

(All BeRex products undergoes a 1 hour, 150 degree C, Anneal bake to eliminate thin whisker growth concerns.)

MSL / ESD Rating

ESD Rating: Class 1B

Value: Passes <1000V

Test: Human Body Model (HBM)

Standard: JEDEC Standard JESD22-A114B

MSL Rating: Level 1 at +265°C convection reflow

Standard: JEDEC Standard J-STD-020



Proper ESD procedures should be followed when handling this device.

NATO CAGE code:

-					
	2	N	9	6	F
	_	1.4	,	U	

BeRex

•website: www.berex.com

• email: sales@berex.com